



# PSMN1R9-40YSD

40 V standard level MOSFET

17 June 2019

Preliminary data sheet

## 1. General description

Standard level gate drive N-channel enhancement mode MOSFET.

## 2. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ °C} \leq T_J \leq 175\text{ °C}$		-	-	40	V
$I_D$	drain current	$V_{GS} = 10\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 2</a>	[1]	-	-	120	A
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 1</a>		-	-	194	W
$T_J$	junction temperature			-55	-	175	°C
<b>Static characteristics</b>							
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_J = 25\text{ °C}$ ; <a href="#">Fig. 8</a>		-	1.6	1.9	mΩ
<b>Dynamic characteristics</b>							
$Q_{GD}$	gate-drain charge	$I_D = 25\text{ A}$ ; $V_{DS} = 20\text{ V}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 10</a> ; <a href="#">Fig. 11</a>		-	8.2	16	nC
$Q_{G(tot)}$	total gate charge			-	57	80	nC

[1] 120A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

## 3. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	<p>LFPAK56; Power-SO8 (SOT669)</p>	<p>mbb076</p>
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain		

## 4. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN1R9-40YSD	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669

## 5. Limiting values

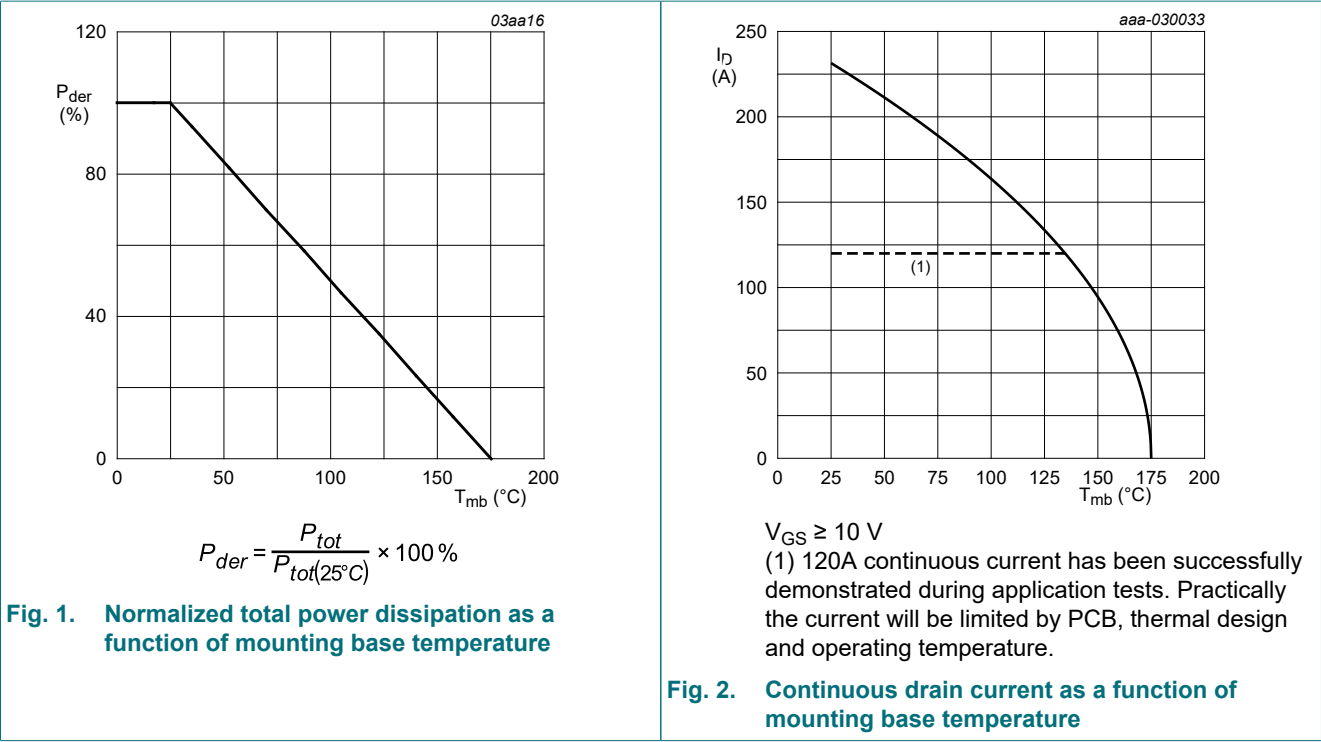
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$		-	40	V
$V_{DSM}$	peak drain-source voltage	$t_p \leq 20\text{ ns}$ ; $f \leq 500\text{ kHz}$ ; $E_{DS(AL)} \leq 200\text{ nJ}$ ; pulsed		-	45	V
$V_{DGR}$	drain-gate voltage	$25\text{ °C} \leq T_j \leq 175\text{ °C}$ ; $R_{GS} = 20\text{ k}\Omega$		-	40	V
$V_{GS}$	gate-source voltage	$T_j \leq 175\text{ °C}$		-20	20	V
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ °C}$ ; Fig. 1		-	194	W
$I_D$	drain current	$V_{GS} = 10\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; Fig. 2	[1]	-	120	A
		$V_{GS} = 10\text{ V}$ ; $T_{mb} = 100\text{ °C}$ ; Fig. 2		-	120	A
$I_{DM}$	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ °C}$		-	926	A
$T_{stg}$	storage temperature			-55	175	°C
$T_j$	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
<b>Source-drain diode</b>						
$I_S$	source current	$T_{mb} = 25\text{ °C}$		-	120	A
$I_{SM}$	peak source current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ °C}$		-	926	A
<b>Avalanche ruggedness</b>						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 60.8\text{ A}$ ; $V_{sup} \leq 40\text{ V}$ ; $R_{GS} = 50\text{ }\Omega$ ; $V_{GS} = 10\text{ V}$ ; $T_{j(init)} = 25\text{ °C}$ ; unclamped; $t_p = 202\text{ }\mu\text{s}$	[2]	-	319	mJ
		$I_D = 25\text{ A}$ ; $V_{sup} \leq 40\text{ V}$ ; $R_{GS} = 50\text{ }\Omega$ ; $V_{GS} = 10\text{ V}$ ; $T_{j(init)} = 25\text{ °C}$ ; unclamped; $t_p = 1.4\text{ ms}$	[2]	-	905	mJ
$I_{AS}$	non-repetitive avalanche current	$V_{sup} = 40\text{ V}$ ; $V_{GS} = 10\text{ V}$ ; $T_{j(init)} = 25\text{ °C}$ ; $R_{GS} = 50\text{ }\Omega$	[2]	-	126	A

[1] 120A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

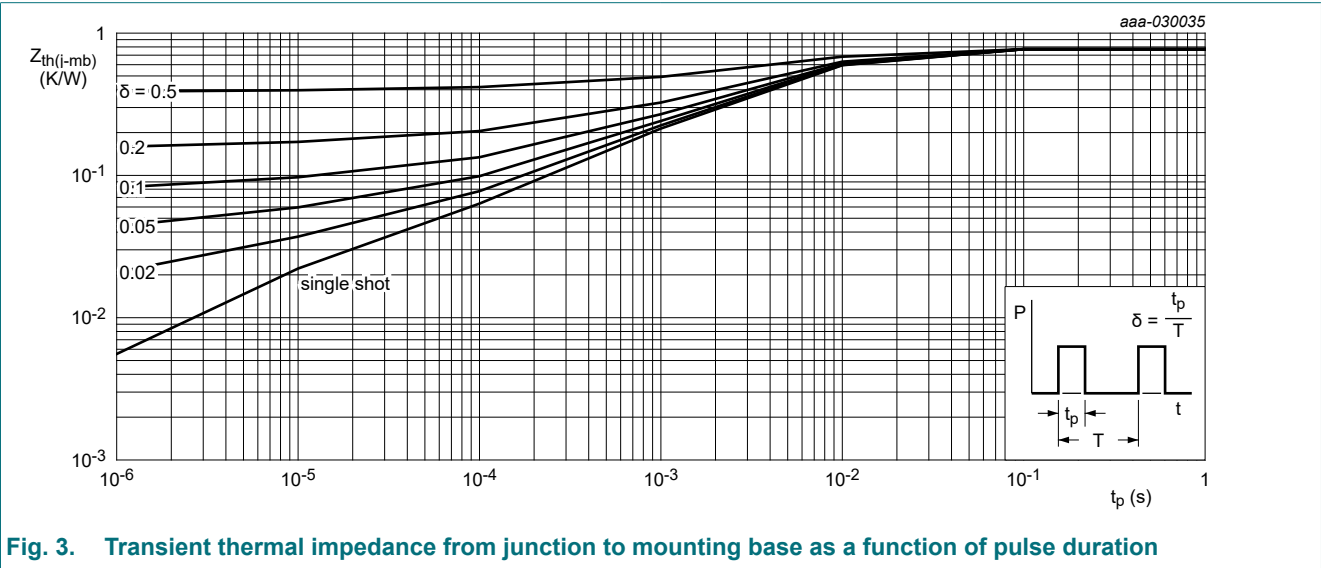
[2] Protected by 100% test

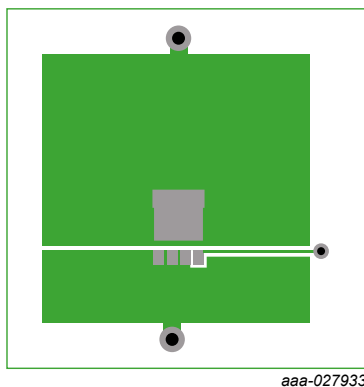


6. Thermal characteristics

Table 5. Thermal characteristics

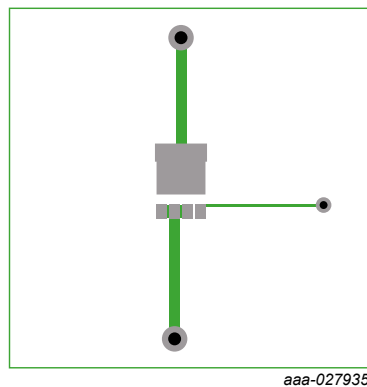
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<a href="#">Fig. 3</a>	-	0.69	0.77	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	<a href="#">Fig. 4</a>	-	42	-	K/W
		<a href="#">Fig. 5</a>	-	85	-	K/W





Copper area 25.4 mm square; 70  $\mu$ m thick on FR4 board

**Fig. 4. PCB layout for thermal resistance from junction to ambient**



70  $\mu$ m thick copper on FR4 board

**Fig. 5. PCB layout with minimum footprint for thermal resistance from junction to ambient**

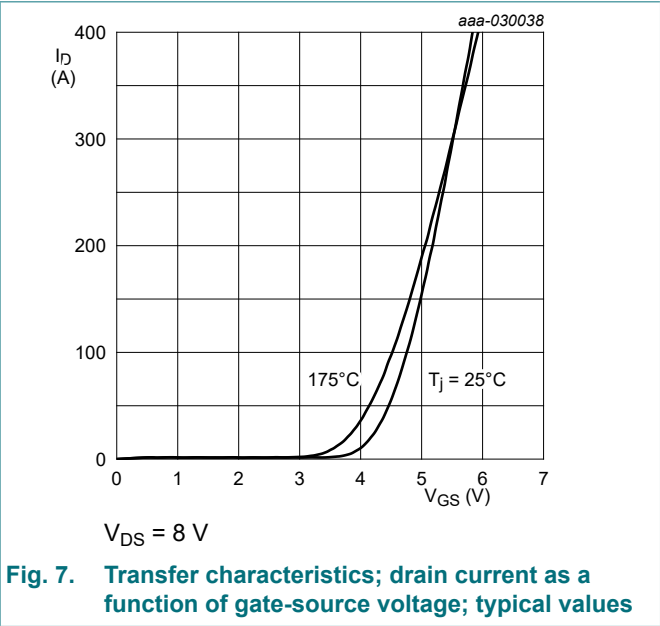
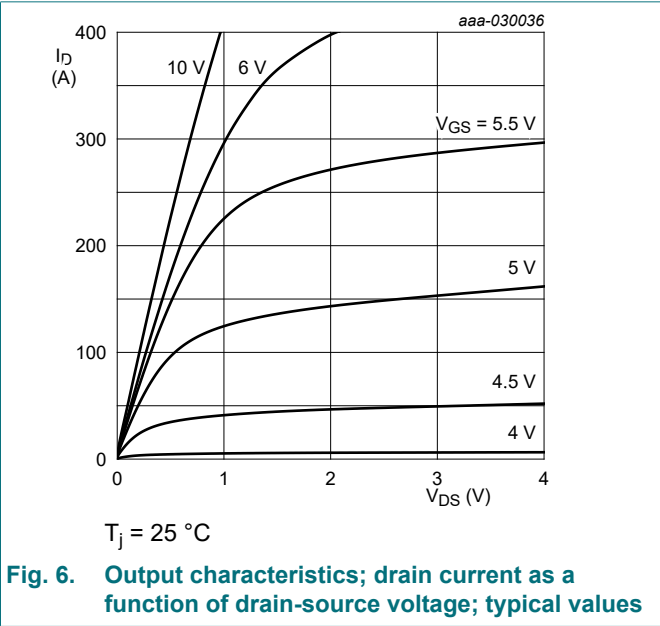
## 7. Characteristics

**Table 6. Characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A$ ; $V_{GS} = 0 V$ ; $T_j = 25 ^\circ C$	40	-	-	V
		$I_D = 250 \mu A$ ; $V_{GS} = 0 V$ ; $T_j = -55 ^\circ C$	36	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA$ ; $V_{DS} = V_{GS}$ ; $T_j = 25 ^\circ C$	2.4	3	3.6	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	$25 ^\circ C \leq T_j \leq 150 ^\circ C$	-	-6.3	-	mV/K
$I_{DSS}$	drain leakage current	$V_{DS} = 32 V$ ; $V_{GS} = 0 V$ ; $T_j = 25 ^\circ C$	-	0.01	1	$\mu A$
		$V_{DS} = 32 V$ ; $V_{GS} = 0 V$ ; $T_j = 125 ^\circ C$	-	[tbd]	-	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25 ^\circ C$	-	2	100	nA
		$V_{GS} = -20 V$ ; $V_{DS} = 0 V$ ; $T_j = 25 ^\circ C$	-	2	100	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 10 V$ ; $I_D = 25 A$ ; $T_j = 25 ^\circ C$ ; <a href="#">Fig. 8</a>	-	1.6	1.9	m $\Omega$
		$V_{GS} = 10 V$ ; $I_D = 25 A$ ; $T_j = 175 ^\circ C$ ; <a href="#">Fig. 9</a>	-	-	3.7	m $\Omega$
$R_G$	gate resistance	$f = 1 MHz$ ; $T_j = 25 ^\circ C$	0.4	1	2.5	$\Omega$
<b>Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$I_D = 25 A$ ; $V_{DS} = 20 V$ ; $V_{GS} = 10 V$ ; <a href="#">Fig. 10</a> ; <a href="#">Fig. 11</a>	-	57	80	nC
		$I_D = 0 A$ ; $V_{DS} = 0 V$ ; $V_{GS} = 10 V$	-	[tbd]	-	nC
$Q_{GS}$	gate-source charge	$I_D = 25 A$ ; $V_{DS} = 20 V$ ; $V_{GS} = 10 V$ ; <a href="#">Fig. 10</a> ; <a href="#">Fig. 11</a>	-	18	27	nC
$Q_{GS(th)}$	pre-threshold gate-source charge		-	12	18	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	5.8	8.7	nC
$Q_{GD}$	gate-drain charge		-	8.2	16	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 25 A$ ; $V_{DS} = 20 V$ ; <a href="#">Fig. 10</a> ; <a href="#">Fig. 11</a>	-	4.4	-	V

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 20 V; V <sub>GS</sub> = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; Fig. 12		-	4427	6198	pF
C <sub>oss</sub>	output capacitance			-	1115	1561	pF
C <sub>rss</sub>	reverse transfer capacitance			-	188	414	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 20 V; R <sub>L</sub> = 0.86 Ω; V <sub>GS</sub> = 10 V; R <sub>G(ext)</sub> = 5 Ω		-	15	-	ns
t <sub>r</sub>	rise time			-	11	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	34	-	ns
t <sub>f</sub>	fall time			-	13	-	ns
Q <sub>oss</sub>	output charge	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 20 V; f = 1 MHz; T <sub>j</sub> = 25 °C		-	37	-	nC
Source-drain diode							
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	0.8	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 25 A; dI <sub>S</sub> /dt = -100 A/μs; V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 20 V; Fig. 13		-	33	-	ns
Q <sub>r</sub>	recovered charge		[1]	-	27	-	nC
t <sub>a</sub>	reverse recovery rise time			-	18	-	ns
t <sub>b</sub>	reverse recovery fall time			-	15	-	ns

[1] includes capacitive recovery



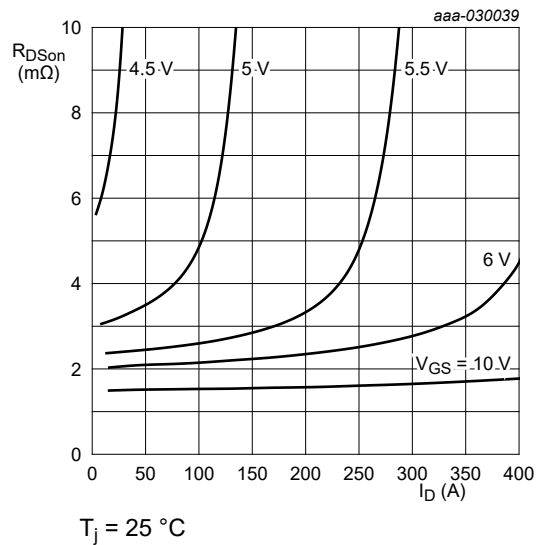


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

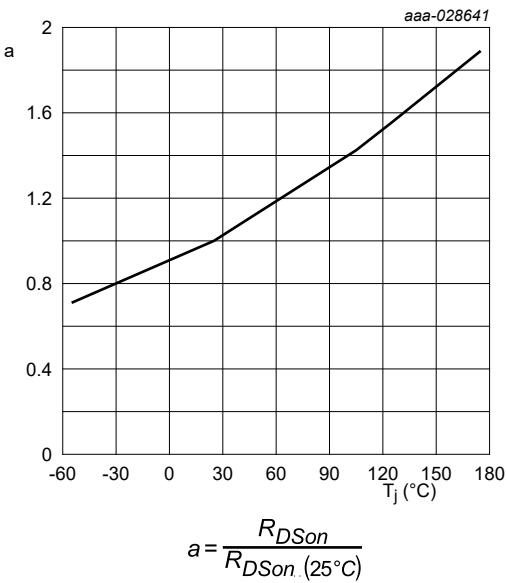


Fig. 9. Normalized drain-source on-state resistance factor as a function of junction temperature

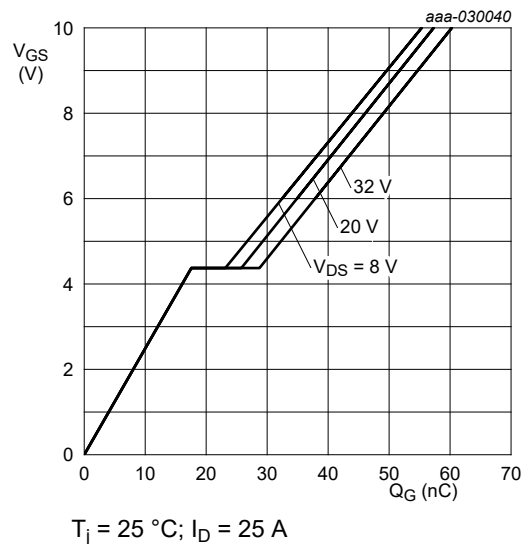


Fig. 10. Gate-source voltage as a function of gate charge; typical values

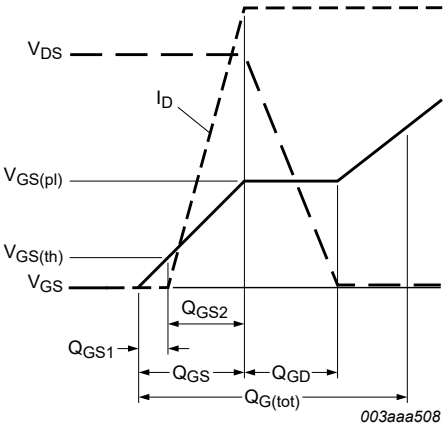
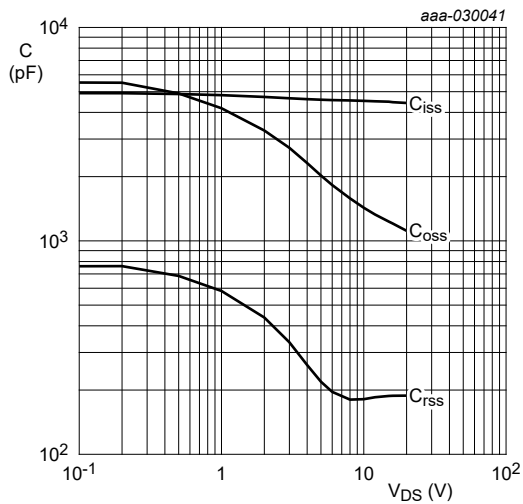
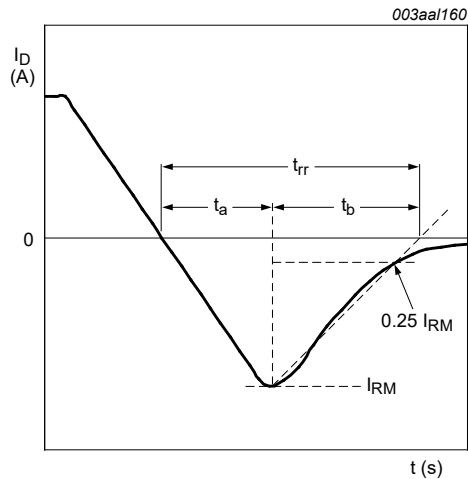


Fig. 11. Gate charge waveform definitions



$V_{GS} = 0 \text{ V}$ ;  $f = 1 \text{ MHz}$

**Fig. 12.** Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



**Fig. 13.** Reverse recovery timing definition

8. Package outline

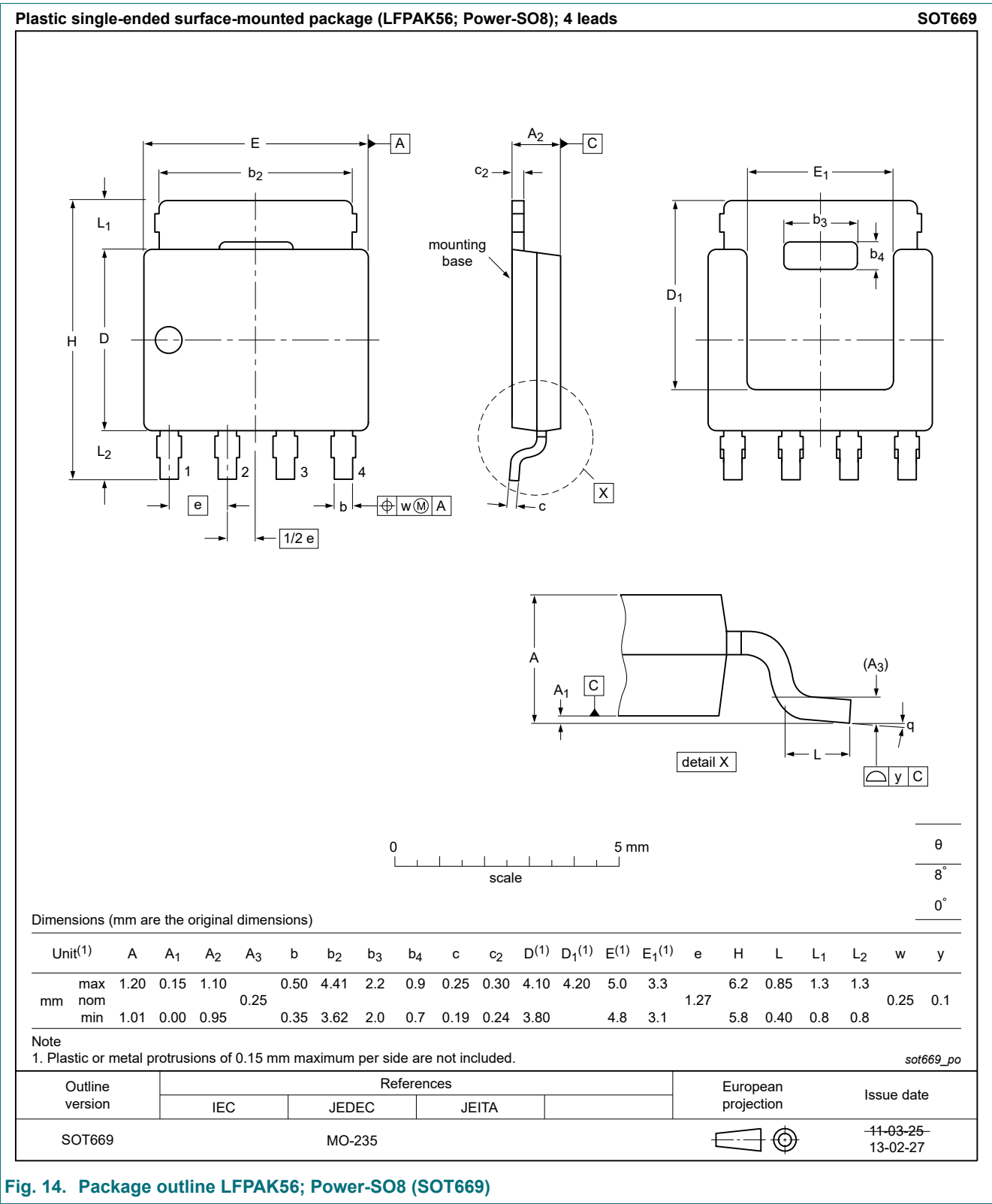


Fig. 14. Package outline LFAK56; Power-SO8 (SOT669)



9. Soldering

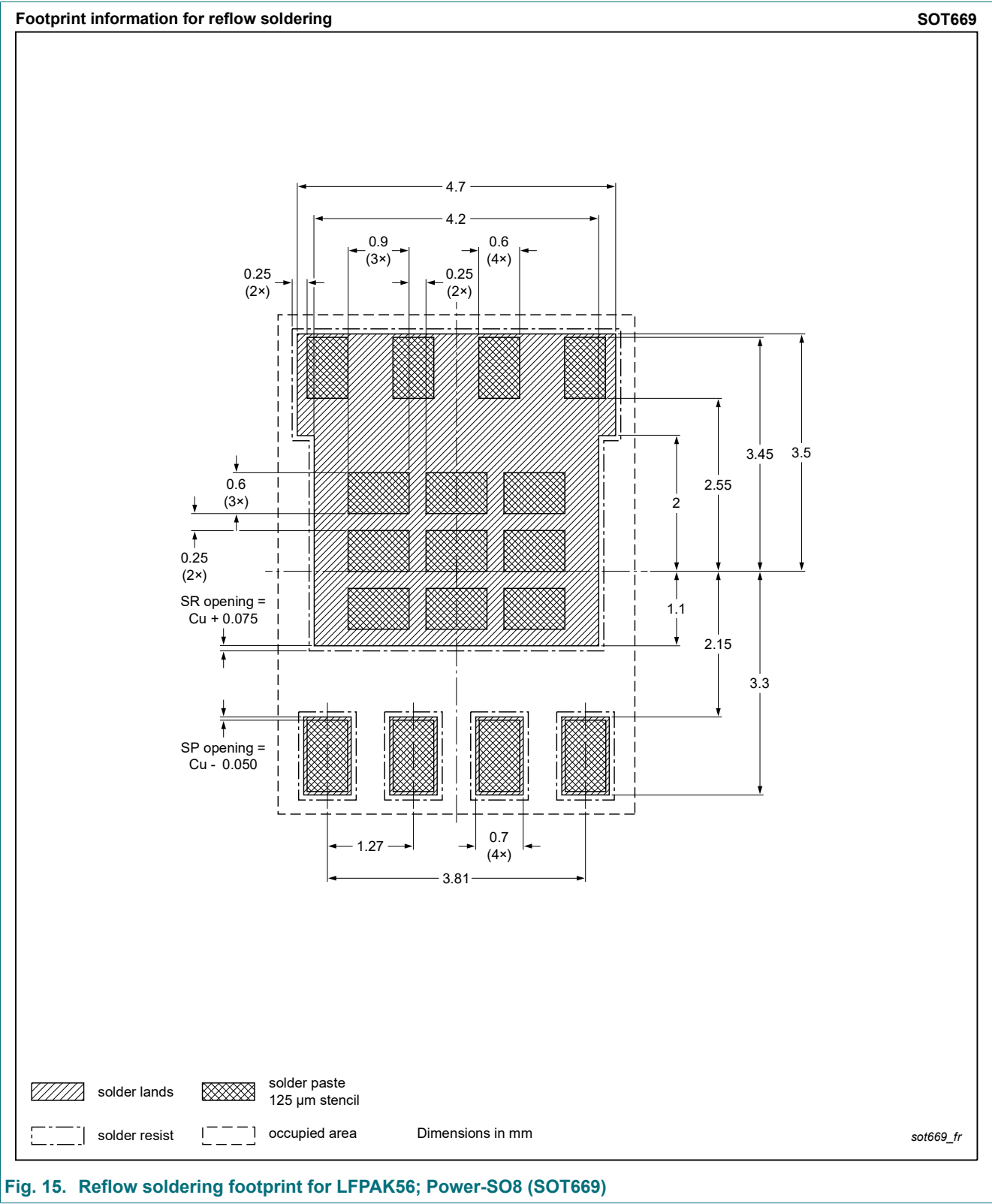


Fig. 15. Reflow soldering footprint for LFP56; Power-SO8 (SOT669)

Wave soldering footprint information for LFPAK56 package

SOT669

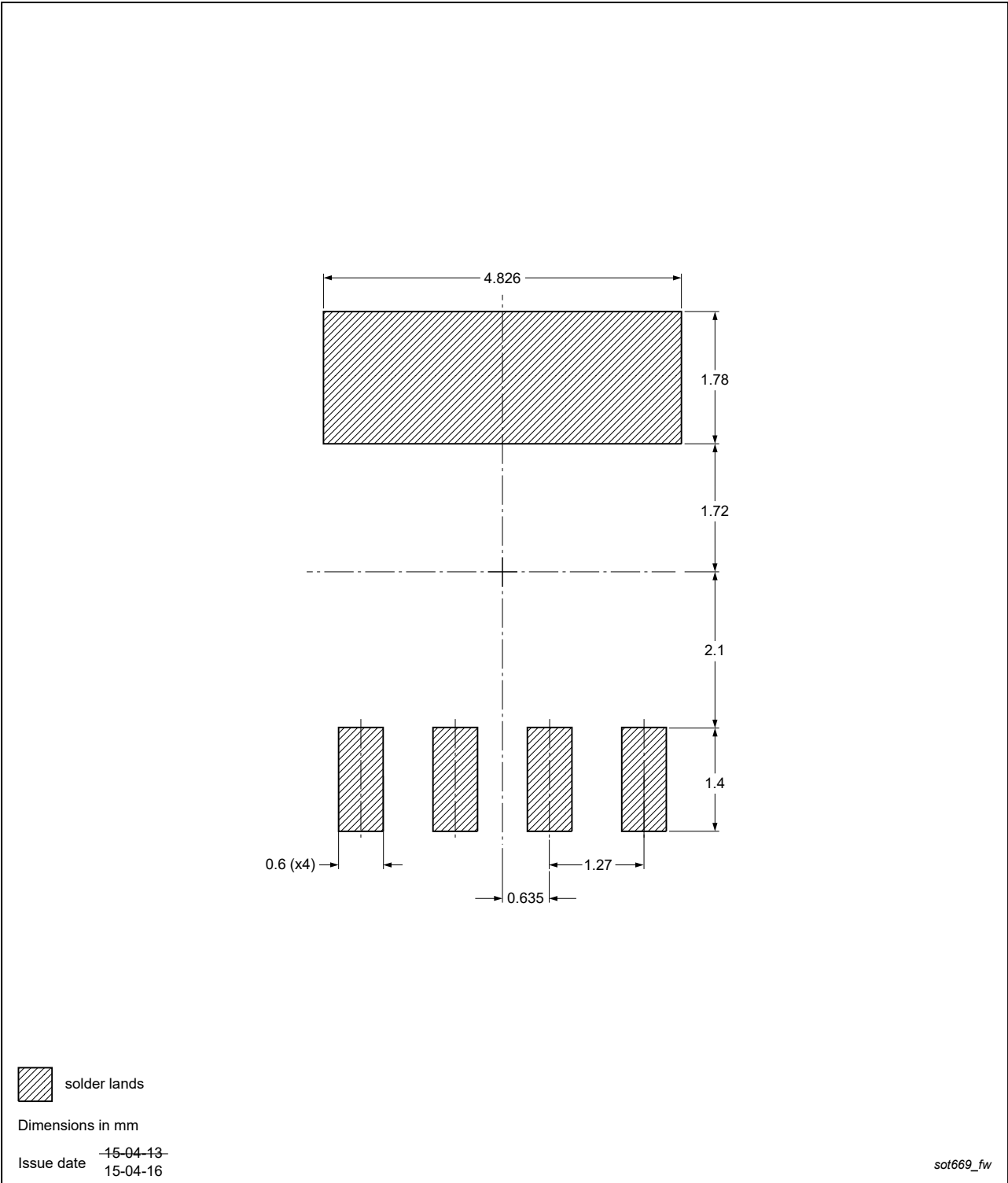


Fig. 16. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

## 10. Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Date of release: 17 June 2019